

March 2006 Advance Information

FHP3194 4:1 High Speed Multiplexer

Features at ±5V

- 0.1dB gain flatness to 155MHz
- 7.5ns channel switching time
- 0.02%/0.03° differential gain/phase error
- 335MHz full power -3dB bandwidth at G=2
- 1600V/µs slew rate
- 60mA output current (easily drives three video loads)
- 70dB channel to channel isolation
- 13mA supply current
- 4mA supply current in disable mode
- 3mA supply current in shutdown mode
- Fully specified at ±5V supplies
- Lead (Pb) free SOIC-14 and TSSOP-14 packages

Applications

- Video switchers and routers
- Multiple Input HDTV switching
- Picture in picture video switch
- Multi-channel ADC Driver

Description

The FHP3194 is a 4:1 analog multiplexer designed for high speed video applications. The output amplifier is a high-speed current feedback amplifier that offers stellar large signal performance of 335MHz -3dB bandwidth and 80MHz 0.1dB bandwidth. The gain of the output amplifier is selectable thru 2 external resistors (R_f and R_g), allowing further flexibility. The $2V_{pp}$ bandwidth performance, 1600V/µs slew rate, and 0.02% / 0.03° differential gain and phase exceed the requirements of high definition television (HDTV) and other multimedia applications. The output amplifier also provides ample output current to drive multiple video loads.

Two address bits (A0 and A1) are used to select one of the four buffered inputs. The FHP3194 offers excellent 7.5ns switching times and better than 70dB channel isolation.

The FHP3194 offers both shutdown and disable capability. During shutdown, the FHP3194 consumes only 3mA of supply current and provides maximum input to output isolation. During disable mode, only the output amplifier is disabled reducing output glitches and allowing for multiplexer expansion.

Functional Block Diagram



Ordering Information

Part Number	Package	Pb-Free	Operating Temperature Range	Packing Method
FHP3194IM14X	SOIC-14	Yes	-40°C to +85°C	Reel
FHP3194IMTC14X	TSSOP-14	Yes	-40°C to +85°C	Reel

Moisture sensitivity level for all parts is MSL-1.

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Advance Information

Pin Configurations



Pin Assignments

Pin#	Pin	Description	
1	IN1	Input, Channel 1	
2	GND	Must be connected to ground	
3	IN2	Input, Channel 2	
4	GND	Must be connected to ground	
5	IN3	Input, Channel 3	
6	-Vs	Negative Supply	
7	IN4	Input, Channel 4	
8	A0	Logic Input A0	
9	A1	Logic Input A1	
10	EN	Enable pin, "1" = Disable, "0" = Enable	
11	SD	Shutdown pin, "1" = Shutdown, "0" = Active	
12	-VIN	Inverting Input of output amplifier	
13	OUT	Output	
14	+Vs	Positive Supply	

Truth Table

A 0	A1	EN	SD	OUT
1	1	0	0	CH4
0	1	0	0	CH3
1	0	0	0	CH2
0	0	0	0	CH1
Х	Х	1	0	Disable
Х	Х	Х	1	Shutdown

Absolute Maximum Ratings

The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Symbol	Parameter	Min	Max	Unit
V _s	Supply Voltage	0	12.6	V
CMIR	Input Voltage Range	-V _s - 0.5V	$+V_{s} + 0.5V$	V

Recommended Operating Conditions

Symbol	Parameter	Min	Тур	Max	Unit
T _c	Operating Temperature Range			+85	°C
Vs	Supply Voltage Range			12	V

Reliability Information

Parameter	Min	Тур	Max	Unit
Junction Temperature			150	°C
Storage Temperature Range	-65		150	°C
Lead Temperature (Soldering, 10s)			300	°C
14-Lead SOIC ¹		128		°C/W
14-Lead TSSOP ¹		130		°C/W

Note:

1. Package thermal resistance (Θ JA), JDEC standard, multi-layer test boards, still air.

ESD Protection

Package	SOIC-14	TSSOP-14
Human Body Model (HBM)	TBD	TBD
Charge Device Model (CDM)	TBD	TBD

Electrical Characteristics at ±5V

 T_c = 25°C, V_s = \pm 5V, R_f = 499 $\Omega,$ R_L = 150 $\Omega,$ G = 2; unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
	Frequency Domain Response					
UGBW	-3dB Bandwidth	$G = +1, V_{OUT} = 0.2V_{pp}$		TBD		MHz
BW _{ss}	-3dB Bandwidth	No Peaking, $G = +2$, $V_{OUT} = 0.2V_{pp}$		380		MHz
BW _{Ls}	Full Power Bandwidth	No Peaking, G = +2, $V_{OUT} = 2V_{pp}$		335		MHz
BW _{0.1dBSS}	0.1dB Gain Flatness	$G = +2, V_{OUT} = 0.2V_{pp}$		155		MHz
BW _{0.1dBLS}	0.1dB Gain Flatness	$G = +2, V_{OUT} = 2V_{pp}$		80		MHz
	Time Domain Response					
t _R , t _F	Rise and Fall Time	V _{OUT} = 2V step; (10% to 90%)		1		ns
t _S	Settling Time to 0.1%	V _{OUT} = 2V step		15		ns
OS	Overshoot	V _{OUT} = 0.2V step		5.7		%
SR	Slew Rate	4V step. G = -1		1600		V/µs
	Distortion / Noise Response					
HD2	2nd Harmonic Distortion	2V _{pp} , 5MHz		-70		dBc
HD3	3rd Harmonic Distortion	2V _{pp} , 5MHz		-79		dBc
THD	Total Harmonic Distortion	2V _{pp} , 5MHz		-81		dB
DG	Differential Gain	NTSC (3.58MHz)		0.02		%
DP	Differenital Phase	NTSC (3.58MHz)		0.03		0
e _n	Input Voltage Noise	> 1MHz		7		nV/Hz
i _{n+}	Input Current Noise (+)	> 1MHz		22		pA/Hz
i _{n-}	Input Current Noise (-)	> 1MHz		16		pA/Hz
X _{TALK}	All Hostile Crosstalk	Channel-to-channel 5MHz/30MHz		-85 / -65		dB
	DC Performance					
V _{IO}	Input Offset Voltage ¹		-9	1	+9	mV
dV _{IO}	Average Drift			8.5		μV/°C
V _{IOM}	Input Offset Voltage Matching ¹	Channel to channel	-5	TBD	5	mV
I _{bn}	Input Bias Current non-inverting ¹	Pins 1,3,5,7	-16	4	16	μA
dl _{bn}	Average Drift			16		nA/°C
I _{bi}	Input Bias Current inverting ¹	Pin 12	-20	13	20	μA
dl _{bn}	Average Drift			85		nA/°C
GM	Gain Matching	Channel-to-channel		0.05		%
PSRR	Power Supply Rejection Ratio ¹	DC	54	60		dB
I _S	Supply Current ¹			13	18	mA
I _{EN}	Disable Supply Current ¹	Disable Mode		4	6	mA
I _{SD}	Shutdown Supply Current ¹	Shutdown Mode		3	5	mA
	Switching Characteristics					
	Switching Time	Channel-to-Channel				
	50% Logic to 10% Output Settling	IN0, IN2 = +0.5V; IN1, IN3 = -0.5V		7.5		ns
	50% Logic to 10% Output Settling	IN0, IN2 = +0.5V; IN1, IN3 = -0.5V		9.1		ns
	50% Logic to 10% Output Settling	IN0, IN2 = +0.5V; IN1, IN3 = -0.5V		25		ns
	Channel Switching Transient (Glitch)	All inputs grounded		104		mV _{nn}

Notes:

1. 100% tested at 25°C

Electrical Characteristics at ±5V continued

Symbol	Parameter	Conditions	Min	Тур	Max	Units
	Digital Inputs					
V _{IH}	Logic High Threshold	A0, A1, EN, and SD pins	2.0			V
V _{IL}	Logic Low Threshold	A0, A1, EN, and SD pins			0.08	V
IIH	Logic Pin Input Current High	A0, A1, EN, and SD pins; Logic Input = 2.0V		TBD		μA
IIL	Logic Pin Input Current Low	A0, A1, EN, and SD pins; Logic Input = 0V		TBD		μA
	Disable Characteristics					
ENISO	Disable Isolation	5MHz / 30MHz		-88 / -72		dB
SDISO	Shutdown Isolation	5MHz / 30MHz		-92 /-77		dB
CH _{ISO}	Channel-to-Channel Isolation	5MHz		-70		dB
ENT _{ON}	Turn on time (Disable to ON)			17		ns
ENT _{OFF}	Turn off time (ON to Disable)			120		ns
SDT _{ON}	Turn on time (Shutdown to ON)			20		ns
SDT _{OFF}	Turn off time (On to Shutdown)			115		ns
	Input Characteristics					
R _{IN}	Input Resistance			TBD		MΩ
C _{IN}	Input Capacitance			TBD		pF
CMIR	Input Common Mode Voltage Range			±2.8		V
CMRR	Common Mode Rejection Ratio ¹	DC, $V_{CM} = \pm 1V$	50	52		dB
	Output Characteristics					
V	Output Voltage Swing1	$R_L = 2k\Omega$		±3.8		V
۷O	Output voltage Swing	$R_L = 150\Omega$	±3.2	±3.7		V
I _{OUT}	Linear Output Current			±60		mA
I _{SC}	Short Circuit Output Current	V _O = GND		±100		mA
D	Output Registeres	enabled		TBD		mΩ
HOUT	Ouipui Resistance	disabled		TBD		MΩ
C _{OUT}	Output Capacitance			TBD		pF

$T_c = 25^{\circ}C$, $V_s = \pm 5V$, $R_f = 499\Omega$, $R_L = 150\Omega$, G = 2; unless otherwise noted.

Notes:

1. 100% tested at 25°C

Mechanical Dimensions

14-Lead Small Outline Package (SOIC)







∕₅∖

b

c

SOIC-14 SYMBOL MIN MAX .0040 .0098 A1 .014 .018 В .0075 .0098 С D .337 .344 Е .150 .157 .050 BSC е н .2284 .2440 h 0099 .0196 .016 .050 А .060 .068 8° 0° ZD 0.20 ref A2 .062 .054

NOTE:

1. All dimensions are in inches.

2. Lead coplanarity should be 0 to 0.10mm (.004") max.

Package surface finishing: (2.1) Top: matte (charmilles #18~30).

- (2.2) All sides: matte (charmilles #18~30).(2.3) Bottom: smooth or matte (charmilles #18~30).
- 4. All dimensions excluding mold flashes and end flash from the package body shall not exceed 0.152mm (.006) per side (d).

14-Lead Outline Package (TSSOP)



A2



ISSOP-14					
SYMBOL	MIN NOM MAX				
А	-	-	1.10		
A1	0.05	-	0.15		
A2	0.85	0.90	0.95		
L	0.50	0.60	0.75		
R	0.09	-	-		
R1	0.09	-	-		
b	0.19	-	0.30		
b1	0.19	0.22	0.25		
С	0.09	-	0.20		
c1	0.09	-	0.16		
0 1	0° – 8°				
L1	1.0 REF				
aaa		0.10			
bbb		0.10			
CCC		0.05			
ddd		0.20			
е		0.65 BSC			
0 2		12° REF			
0 3		12° REF			
D	4.90	5.00	5.10		
E1	4.30 4.40 4.50				
E	6.4 BSC				
е		0.65 BSC			
N		14			

NOTES:

- 1 All dimensions are in millimeters (angle in degrees).
- 2 Dimensioning and tolerancing per ASME Y14.5-1994.
- 🖄 Dimensions "D" does not include mold flash, protusions or gate burrs. Mold flash protusions or gate burrs shall not exceed 0.15 per side .
- A Dimension "E1" does not include interlead flash or protusion. Interlead flash or protusion shall not exceed 0.25 per side.
- A Dimension "b" does not include dambar protusion. Allowable dambar protusion shall be 0.08mm total in excess of the "b" dimension at maximum material condition. Dambar connot be located on the lower radius of the foot. Minimum space between protusion and adjacent lead is 0.07mm for 0.5mm pitch packages.
- Terminal numbers are shown for reference only.
- \triangle Datums -A- and -B- to be determined at datum plane -H-.
- & Dimensions "D" and "E1" to be determined at datum plane -H-
- A This dimensions applies only to variations with an even number of leads per side. For variation with an odd number of leads per side, the "center" lead must be coincident with the package centerline, Datum A.
- Cross sections A A to be determined at 0.10 to 0.25mm from the leadtip.

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